3.2.7. Diode Parameters

Diode parameters except breakdown voltages and Zener diode parameters are characterisation parameters (refer to section "Introduction").

NDIFF - PWELL

PASS/FAIL PARAMETERS						
Parameter	Symbol	Min	Тур	Max	Unit	Note
breakdown voltage	BVN	7	9		V	30
INFORMATION PARAMETERS						
area junction capacitance	CJN		0.94		fF/µm²	29
area grading coefficient	MJN		0.34		-	29
junction potential	PBN		0.69		V	29
sidewall junction capacitance	CJSWN		0.25		fF/µm	29
sidewall grading coefficient	MJSWN		0.23		-	29
area leakage current	JSN		0.01		fA/µm²	31
sidewall leakage current	JSSWN		0.13		fA/µm	31

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PASS/FAIL PARAMETERS					
breakdown voltage	BVP	-7	-9	V	30
INFORMATION PARAMETERS					
area junction capacitance	CJP		1.36	fF/µm²	29
area grading coefficient	MJP		0.56	-	29
junction potential	PBP		1.02	V	29
sidewall junction capacitance	CJSWP		0.32	fF/µm	29
sidewall grading coefficient	MJSWP		0.43	-	29
area leakage current	JSP		0.09	fA/µm²	31
sidewall leakage current	JSSWP		0.61	fA/µm	31

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